## NSN 5961-00-584-4575

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-584-4575 **Inclosure Material:** Ceramic **Overall Length:** 0.350 inches **Overall Height:** 0.070 inches **Overall Width:** 0.500 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 25.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes drain current all transistor and 50.00 milliamperes gate current all transistor **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 82577-928162 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**